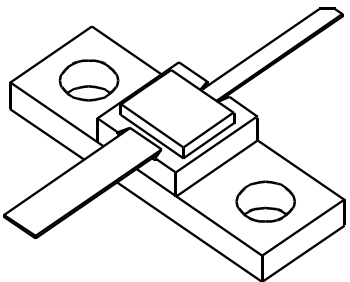




2223-1.7

1.7 Watts - 24 Volts, Class C
Microwave 2200 - 2300 MHz

| | |
|---|--|
| <p>GENERAL DESCRIPTION</p> <p>The 2223-1.7 is a COMMON BASE transistor capable of providing 1.7 Watts of Class C, RF output power over the band 2200 - 2300 MHz. This transistor is designed for Microwave Broadband Class C amplifier applications. It includes input prematching and utilizes Gold metalization and diffused ballasting to provide high reliability and supreme ruggedness. The transistor uses a fully hermetic High Temperature Solder sealed package.</p> | <p>CASE OUTLINE 55LV, STYLE 1</p>  |
| <p>ABSOLUTE MAXIMUM RATINGS</p> <p>Maximum Power Dissipation @ 25°C 7 Watts</p> <p>Maximum Voltage and Current</p> <p>BVces Collector to Emitter Voltage 45 Volts BVebo Emitter to Base Voltage 3.5 Volts Ic Collector Current .25 Amps</p> <p>Maximum Temperatures</p> <p>Storage Temperature - 65 to + 200°C Operating Junction Temperature + 200°C</p> | |

ELECTRICAL CHARACTERISTICS @ 25 °C

| SYMBOL | CHARACTERISTICS | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|--------|-------------------------|-------------------|-----|-----|------|-------|
| Pout | Power Output | F = 2.2 - 2.3 GHz | 1.7 | | | Watts |
| Pin | Power Input | Vcc = 24 Volts | | | .25 | Watts |
| Pg | Power Gain | | 8.3 | | | dB |
| ηc | Efficiency | | | 35 | | % |
| VSWR | Load Mismatch Tolerance | | | | 10:1 | |

| | | | | | | |
|-------|-----------------------------|-----------------------|-----|--|-----|-------|
| BVces | Collector to Base Breakdown | Ic = 10 mA | 40 | | | Volts |
| BVebo | Emitter to Base Breakdown | Ie = 2 mA | 3.5 | | | Volts |
| Hfe | Current Gain | Vce = 5 V, Ic = 160mA | 10 | | 100 | |
| Cob | Output Capacitance | Vcb = 28V, 1MHz | | | | pF |
| θjc | Thermal Resistance | Tc = 25 °C | | | 24 | °C/W |

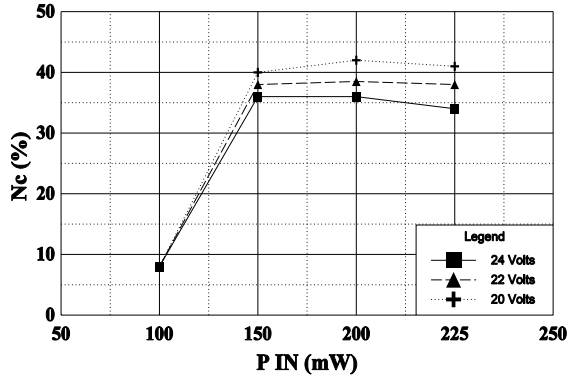
Issue A June 1997

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GHZ Technology Inc. 3000 Oakmead Village Drive, Santa Clara, CA 95051-0808 Tel. 408 / 986-8031 Fax 408 / 986-8120

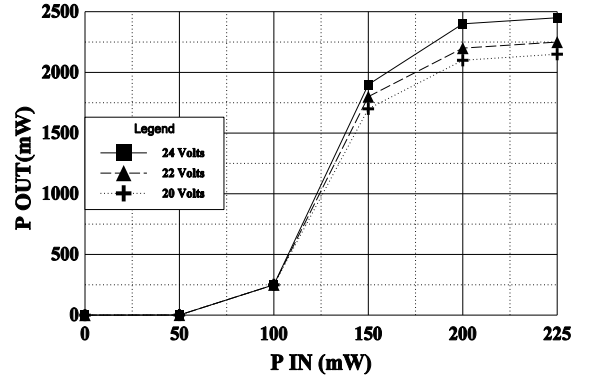
EFFICIENCY VS POWER IN

FREQUENCY=2.25 GHz



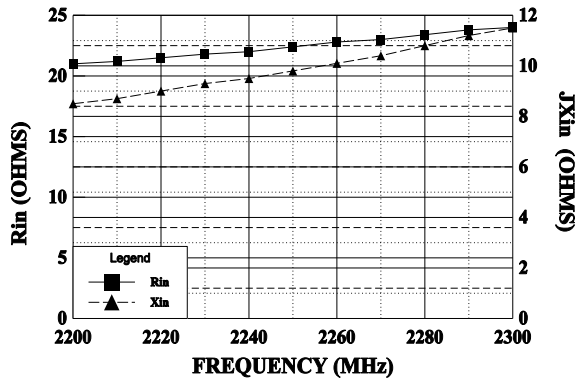
POWER OUTPUT VS POWER INPUT

FREQUENCY=2.25 GHz



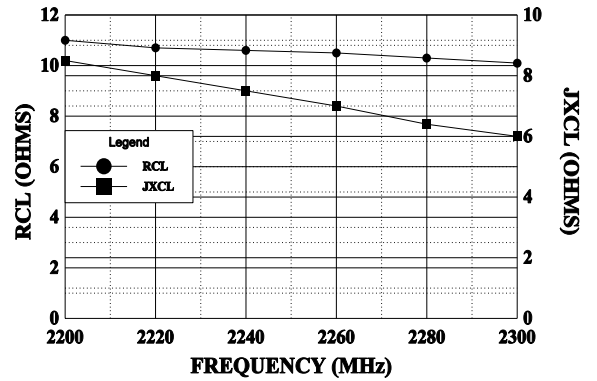
INPUT IMPEDANCE

Vcc=22V, Pin=.25W



LOAD IMPEDANCE

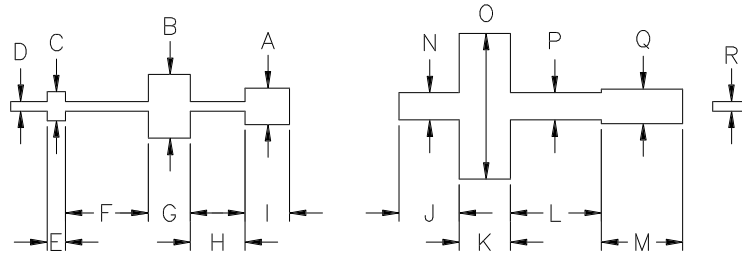
Vcc=22V, Pin=.25W



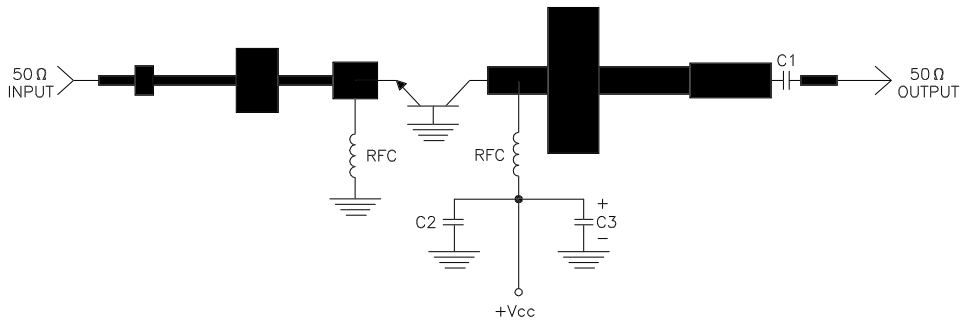
REVISIONS

| ZONE | REV | DESCRIPTION | DATE | APPROVED |
|------|-----|-------------|------|----------|
|------|-----|-------------|------|----------|

| DIM | INCHES |
|-----|--------|
| A | .200 |
| B | .350 |
| C | .160 |
| D | .053 |
| E | .100 |
| F | .455 |
| G | .230 |
| H | .300 |
| I | .245 |
| J | .330 |
| K | .270 |
| L | .500 |
| M | .445 |
| N | .150 |
| O | .800 |
| P | .150 |
| Q | .190 |
| R | .053 |



2223-1.7 TEST CIRCUIT



DIELECTRIC = 19.4 MIL THICK TFE Er = 2.43
 C1, C2 = 62pF CHIP ATC "A"
 C3 = 10MFD @ 35V
 RFC = 4 turns #22 wire on 1/16" dia.



| | | |
|---------------|---------------------|----------|
| CAGE 0PJR2 | DWG NO. 2223-1.7 | REV A |
| SCALE 1/1 | SHEET | |